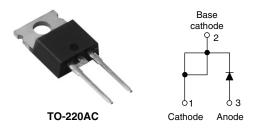


## High Performance Schottky Generation 5.0, 20 A



PRODUCT SUMMARY				
I <sub>F(AV)</sub>	20 A			
$V_{R}$	100 V			
V <sub>F</sub> at 20 A at 125 °C	0.67 V			

#### **FEATURES**

- 175 °C high performance Schottky diode
- Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V<sub>F</sub> vs. I<sub>R</sub> trade off for high efficiency
- · Increased ruggedness for reverse avalanche capability
- RBSOA available
- · Negligible switching losses
- · Submicron trench technology
- Full lead (Pb)-free and RoHS compliant devices
- Designed and qualified for industrial level

#### **APPLICATIONS**

- High efficiency SMPS
- · Automotive
- · High frequency switching
- · Output rectification
- · Reverse battery protection
- · Freewheeling
- · Dc-to-dc systems
- · Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
V <sub>RRM</sub>		100	V				
V <sub>F</sub>	20 Apk, T <sub>J</sub> = 125 °C (typical)	0.63	v				
T <sub>J</sub>	Range	- 55 to 175	°C				

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	20TT100	UNITS
Maximum DC reverse voltage	$V_R$	T <sub>J</sub> = 25 °C	100	V

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDIT	VALUES	UNITS		
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 160 °C, re	50 % duty cycle at T <sub>C</sub> = 160 °C, rectangular waveform			
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	900	Α	
	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	300		
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.5 A, L = 60 mH		67.5	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J \text{ max. } I_{AS}$ at $T_J \text{ max. }$ as a function of time pulse See fig. 8		I <sub>AS</sub> at T <sub>J</sub> max.	Α	

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## High Performance Schottky Generation 5.0, 20 A



ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	TYP.	MAX.	UNITS	
	20 A T 05 00		-	0.8			
Forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	40 A	T <sub>J</sub> = 25 °C	-	0.95	V	
Torward voltage drop	V FM (1)	20 A	T 405 00	-	0.67		
		40 A	T <sub>J</sub> = 125 °C	-	0.8		
Reverse leakage current	I <sub>RM</sub> (1)	T <sub>J</sub> = 25 °C	V Datad V	-	150	μΑ	
neverse leakage current	IRM \''	$T_J = 125  ^{\circ}\text{C}$ $V_R = \text{Rated } V_R$	=	6	mA		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz) 25 °C		850	-	pF	
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	-	nΗ	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs	

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	e	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C
Maximum thermal resistar junction to case	nce,	R <sub>thJC</sub>	DC operation	2	°C/W
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.5	- C/VV
Approximate weight				2	g
Approximate weight				0.07	OZ.
minimum				6 (5)	kgf · cm
Mounting torque	maximum			12 (10)	(lbf ⋅ in)
Marking device			Case style TO-220AC	20TT100	



# High Performance Vishay High Power Products Schottky Generation 5.0, 20 A

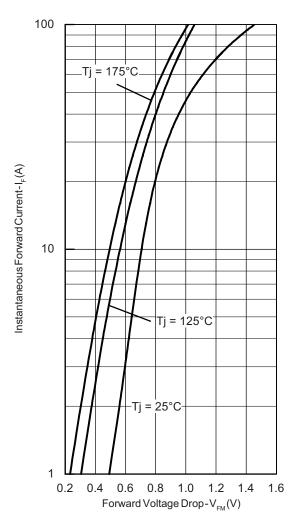


Fig. 1 - Maximum Forward Voltage Drop Characteristics

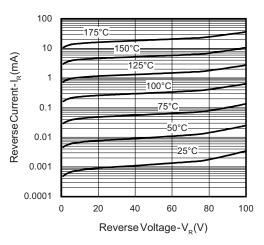


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

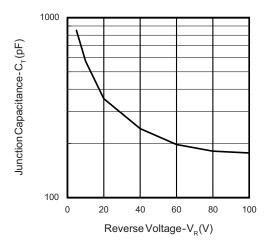


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

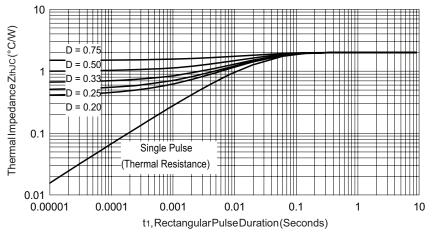


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

### High Performance Schottky Generation 5.0, 20 A



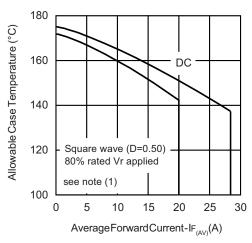


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

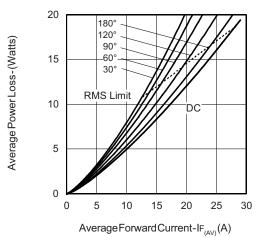
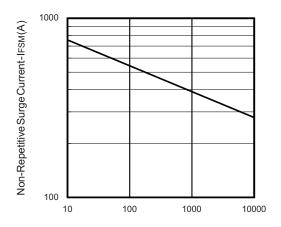


Fig. 6 - Forward Power Loss Characteristics



 $Square Wave Pulse Duration-t_{_{p}}(microsec)$ 

Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>



# High Performance Vishay High Power Products Schottky Generation 5.0, 20 A

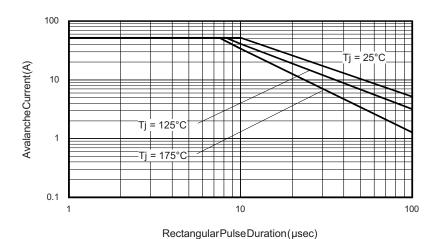


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

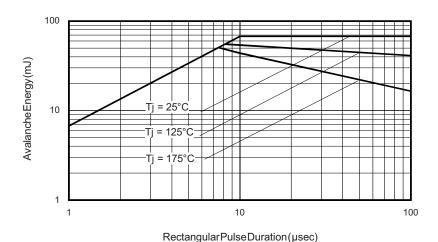


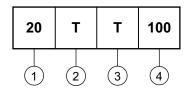
Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

### High Performance Schottky Generation 5.0, 20 A



#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Current rating (20 A)

2 - Package:

T = TO-220

3 - T = Trench

4 - Voltage code (100 V)

Tube standard pack quantity: 50 pieces

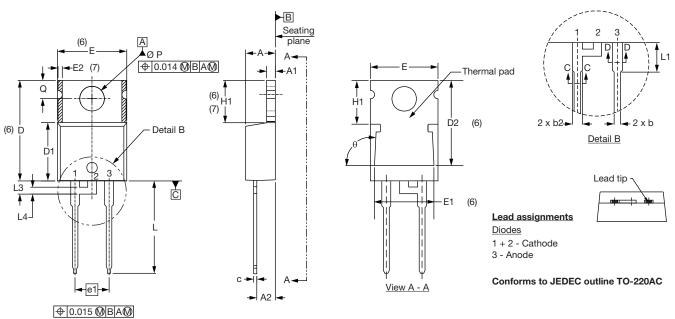
LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95221				
Part marking information	http://www.vishay.com/doc?95224			
SPICE model	http://www.vishay.com/doc?95228			



## Vishay Semiconductors

### **TO-220AC**

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIMBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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